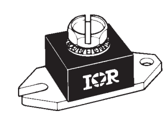
International
IOR Rectifier

120NQ...(R) SERIES

SCHOTTKY RECTIFIER

120 Amp



D-67

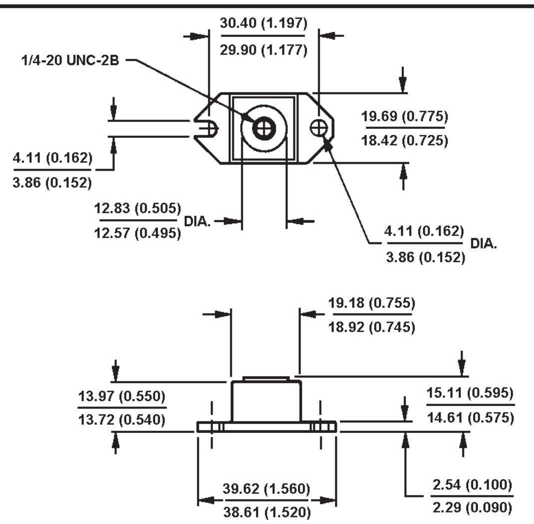
Major Ratings and Characteristics

Characteristics	120NQ...(R)	Units
$I_{F(AV)}$ Rectangular waveform	120	A
V_{RRM} range	35 to 45	V
I_{FSM} @ tp = 5 µs sine	29,000	A
V_F @120Apk, T_J=125°C	0.52	V
T_J range	-55 to 150	°C

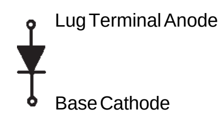
Description/Features

The 120NQ...(R) high current Schottky rectifier module series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

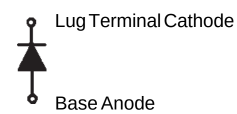
- 150° C T_J operation
- Unique high power, Half-Pak module
- Replaces two parallel DO-5's
- Easier to mount and lower profile than DO-5's
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



120NQ045



120NQ045R



Outline D-67 HALF PAK Module
Dimensions in millimeters and (inches)

Voltage Ratings

	Part number	120NQ035(R)	120NQ040(R)	120NQ045(R)
V_R	Max. DC Reverse Voltage (V)	35	40	45
V_{RWM}	Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

	Parameters	120NQ	Units	Conditions	
$I_{F(AV)}$	Max. Average Forward Current * See Fig. 5	120	A	50% duty cycle @ T_C = 106° C, rectangular wave form	
I_{FSM}	Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	29,000	A	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied
		1550		10ms Sine or 6ms Rect. pulse	
E_{AS}	Non-Repetitive Avalanche Energy	81	mJ	T_J = 25 °C, I_{AS} = 12 Amps, L = 1.12 mH	
I_{AR}	Repetitive Avalanche Current	12	A	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A = 1.5 x V_R typical	

Electrical Specifications

	Parameters	120NQ	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop (1) * See Fig. 1	0.57	V	@ 120A	T_J = 25 °C
		0.73	V	@ 240A	
		0.52	V	@ 120A	T_J = 125 °C
		0.69	V	@ 240A	
I_{RM}	Max. Reverse Leakage Current (1) * See Fig. 2	10	mA	T_J = 25 °C	V_R = rated V_R
		500	mA	T_J = 125 °C	
$V_{F(TO)}$	Threshold Voltage	0.32	V	T_J = T_J max.	
r_t	Forward Slope Resistance	1.37	mΩ		
C_T	Max. Junction Capacitance	5200	pF	V_R = 5V_{DC}, (test signal range 100Khz to 1Mhz) 25 °C	
L_S	Typical Series Inductance	7.0	nH	From top of terminal hole to mounting plane	
dv/dt	Max. Voltage Rate of Change (Rated V_R)	10,000	V/ µs		

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters		120NQ	Units	Conditions
T_J	Max. Junction Temperature Range		-55 to 150	°C	
T_{stg}	Max. Storage Temperature Range		-55 to 150	°C	
R_{thJC}	Max. Thermal Resistance Junction to Case		0.40	°C/W	DC operation * See Fig. 4
R_{thCS}	Typical Thermal Resistance, Case to Heatsink		0.15	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		25.6 (0.9)	g (oz.)	
T	Mounting Torque	Min.	17 (15)	Kg-cm (lbf-in)	Non-lubricated threads
		Max.	29 (25)		
	Terminal Torque	Min.	23 (20)		
		Max.	46 (40)		
	Case Style		HALF PAK Module		

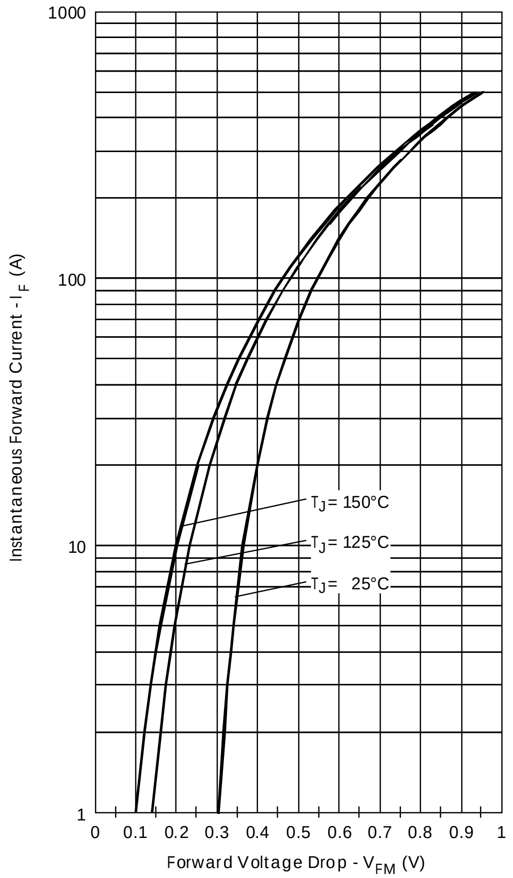


Fig. 1 - Maximum Forward Voltage Drop Characteristics

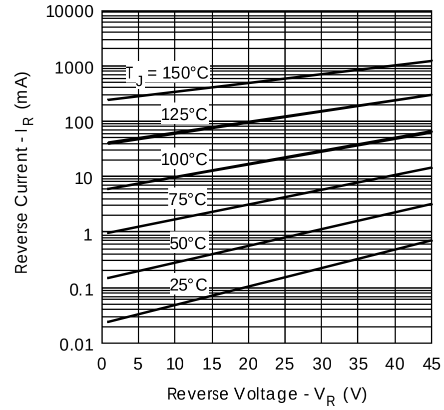


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

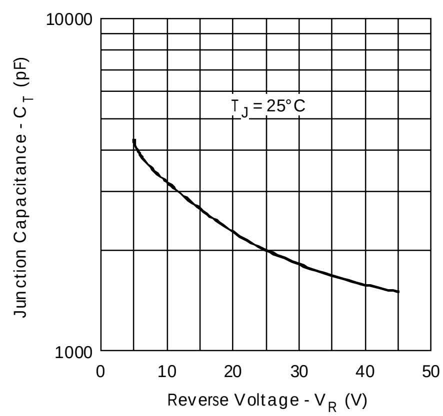


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

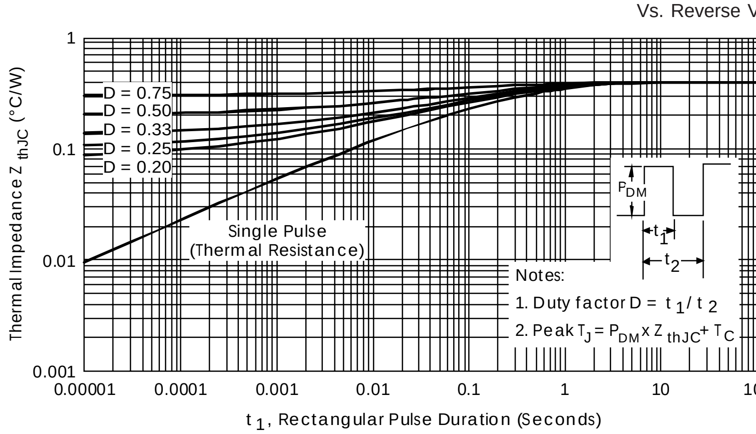


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

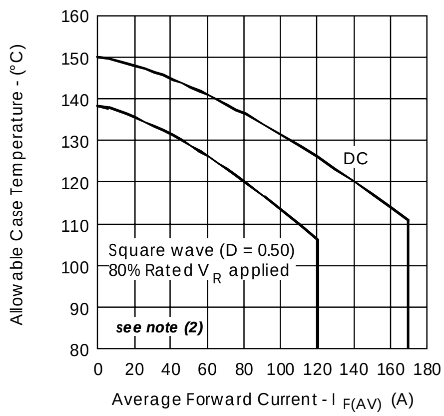


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

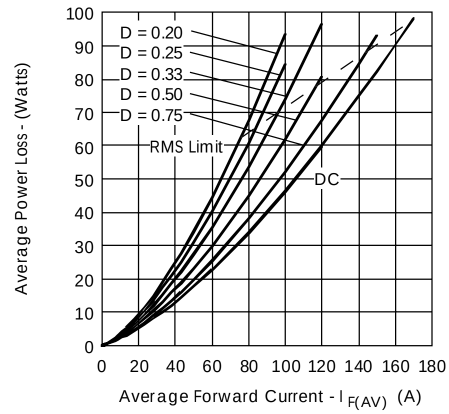


Fig. 6 - Forward Power Loss Characteristics

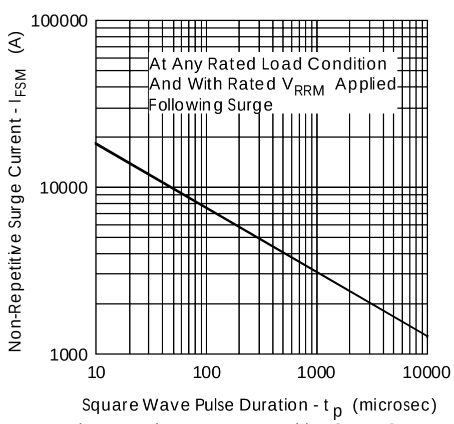


Fig. 7 - Maximum Non-Repetitive Surge Current

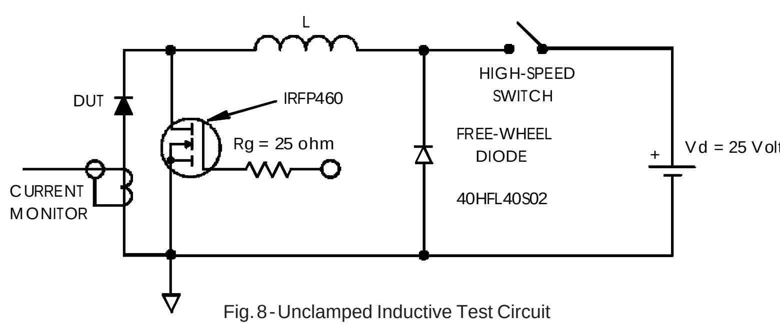


Fig. 8 - Unclamped Inductive Test Circuit

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM}$ @ $(I_{F(AV)} / D)$ (see Fig. 6);
Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; I_R @ V_{R1} = 80% rated V_R